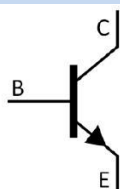


TO-92 NPN Silicon NPN transistor in a TO-92 Plastic Package.

, h_{FE} , , KTA1267
 High DC current gain, excellent h_{FE} linearity, low noise, complementary to KTA1267.

General amplifier and switching application.



PIN1 Base PIN 2 Collector PIN 3 Emitter

h_{FE} Classifications Symbol	O	Y	GR	BL
h_{FE} Range	70~140	120~240	200~400	350~700

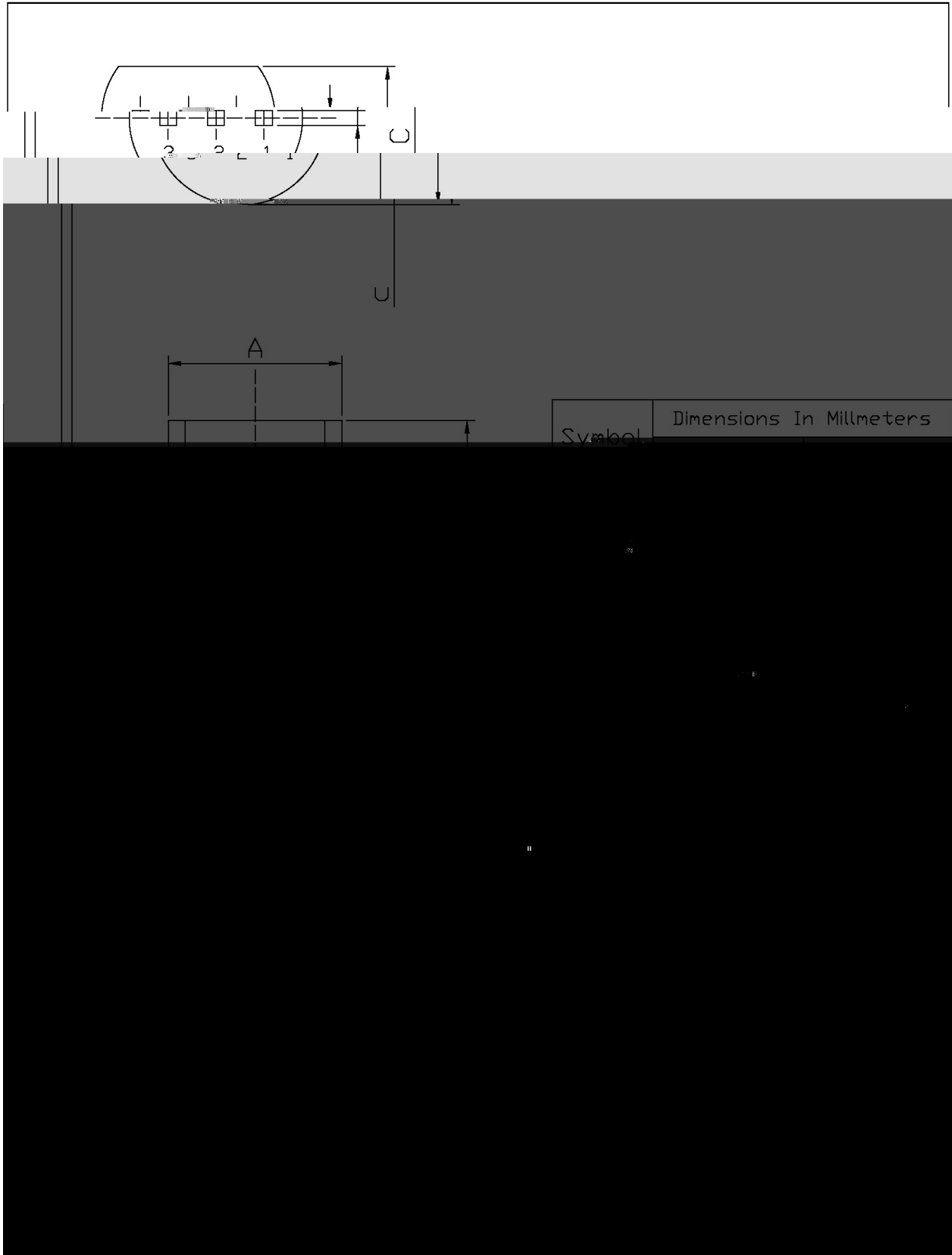
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	50	V
Collector to Emitter Voltage	V_{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	150	mA
Emitter Current - Continuous	I_E	-150	mA
Collector Power Dissipation	P_C	400	mW
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

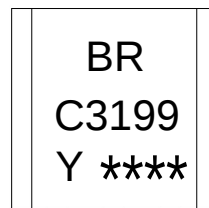
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=50V$ $I_E=0$			0.1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=5.0V$ $I_C=0$			0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=6.0V$ $I_C=2.0mA$	70		700	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA$ $I_B=10mA$		0.1	0.25	V
Transition Frequency	f_T	$V_{CE}=10V$ $I_C=1.0mA$	80			MHz
Collector Capacitance	C_{ob}	$V_{CB}=10V$ $f=1.0MHz$ $I_E=0$		2.0	3.5	pF
Noise Figure	NF	$V_{CE}=6.0V$ $I_C=0.1mA$ $f=1.0KHz$ $R_g=10K\Omega$		1.0	10	dB



T0-92

Unit: mm





BR:

C3199

Y:

h_{FE}

Note:

BR:

Company Code.

C3199:

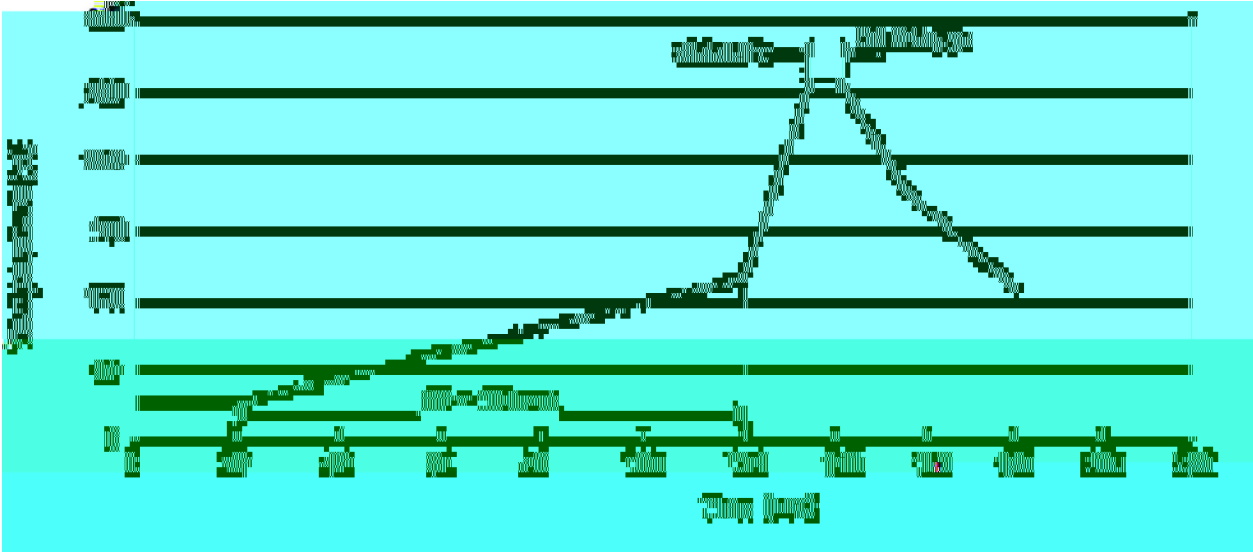
Product Type.

Y:

h_{FE} Classifications Symbol

****:

Lot No. Code,code change with Lot No.



Note:			
1	25 150	60 90sec;	1.Preheating:25~150 , Time:60~90sec.
2	255±5	5±0.5sec;	2.Peak Temp.:255±5 , Duration:5±0.5sec.
3	2 10	/sec.	3. Cooling Speed: 2~10 /sec.

270±5	10±1 sec.	Temp:270±5℃	Time:10±1 sec
-------	-----------	-------------	---------------

/ BULK